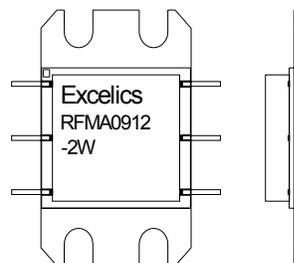


### FEATURES

- 9.50– 11.70GHz Operating Frequency Range
- 32.5dBm Output Power at 1dB Compression
- 30.0 dB Typical Power Gain @ 1dB Gain Compression
- -41dBc Typical OIM3 @ each tone Pout 21.5dBm

### APPLICATIONS

- Point-to-point and point-to-multipoint radio
- Military Radar Systems



Caution! ESD sensitive device.

### ELECTRICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C, 50 ohm, V<sub>dd</sub>=7V, V<sub>gg</sub>=-5V)

SYMBOL	PARAMETER/TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>F</b>	Operating Frequency Range	9.50		11.70	GHz
<b>P1dB</b>	Output Power at 1dB Gain Compression	31.5	32.5		dBm
<b>G1dB</b>	Gain @ 1dB gain compression	27.0	30.0		dB
<b>OIMD3</b>	Output 3 <sup>rd</sup> Order Intermodulation Distortion @Δf=10MHz, Each Tone Pout 21.5dBm		-41	-38	dBc
<b>Input RL</b>	Input Return Loss		-12	-8	dB
<b>Output RL</b>	Output Return Loss		-15	-10	dB
<b>I<sub>dd</sub></b>	Drain Current		1900	2150	mA
<b>V<sub>dd</sub></b>	Drain Voltage		7	8	V
<b>V<sub>gg</sub></b>	Gate Voltage		-5		V
<b>R<sub>th</sub></b>	Thermal Resistance (Au-Sn Eutectic Attach)		4.0	4.5	°C/W
<b>T<sub>b</sub></b>	Operating Base Plate Temperature	-30		+80	°C

### MAXIMUM RATINGS @25°C

SYMBOL	CHARACTERISTIC	ABSOLUTE	CONTINUOUS <sup>1,2</sup>
<b>V<sub>DD</sub></b>	Drain Supply Voltage	12V	8V
<b>V<sub>GG</sub></b>	Gate Supply Voltage	-8V	-3V
<b>I<sub>DD</sub></b>	Drain Current	I <sub>dss</sub>	3.6A
<b>I<sub>GG</sub></b>	Gate Current	240mA	40mA
<b>P<sub>IN</sub></b>	Input Power	20dBm	@ 3dB compression
<b>T<sub>CH</sub></b>	Channel Temperature	175°C	150°C
<b>T<sub>STG</sub></b>	Storage Temperature	-65/175°C	-65/150°C
<b>P<sub>T</sub></b>	Total Power Dissipation	30.0W	25.2W

1. Operating the device beyond any of the above rating may result in permanent damage.

2. Bias conditions must also satisfy the following equation  $V_{dd} \cdot I_{dd} < (T_{CH} - T_b) / R_{TH}$ ; where T<sub>b</sub> = operating base plate temperature

Specifications are subject to change without notice.

Excelics Semiconductor, Inc. 310 De Guigne Drive, Sunnyvale, CA 94085

Phone: 408-737-1711 Fax: 408-737-1868 Web: [www.excelics.com](http://www.excelics.com)

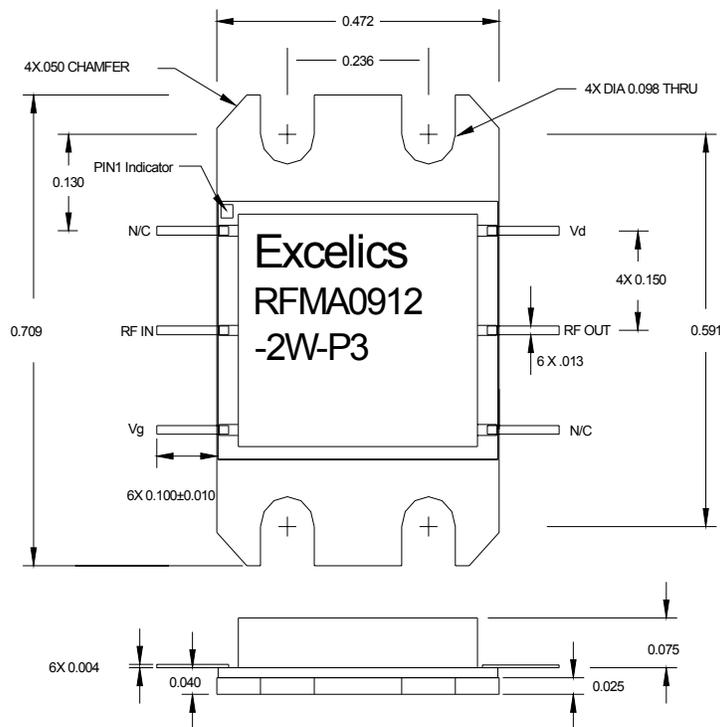
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Revised October 2007

UPDATED 10/05/2007

## 9.50 – 11.70 GHz Power Amplifier MMIC

### P3 Package Outline



All dimensions in inches

#### DISCLAIMER

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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